

#### **Unipolar Hall Effect Switch IC**

#### **Features:**

- Operates from 2.4V to 26V supply voltage with reverse voltage protection
- Operates with magnetic fields from DC to 15kHz
- On-chip Hall Sensor
- On-chip temperature compensation circuitry minimizes shifts in on and off points and hysteresis over temperature and supply voltage
- Ideal sensor for speed measurement, revolution counting, positioning, and DC brushless motors
- On (L) with magnetic South pole and Off(H) without magnetic field or with magnetic North pole

#### **Functional Description:**

WSH130NL is designed to integrate Hall sensor with output driver together on the same chip, it is suitable for speed measurement, revolution counting, positioning. It includes a temperature compensated voltage regulator, a differential amplifier, a Hysteresis controller and a open-collector output driver capable of sinking up to 20mA current load. An on-chip protection resistor is implemented to prevent reverse power fault.

The temperature-dependent bias increases the supply voltage of the hall plates and adjusts the switching points to the decreasing induction of magnets at higher temperatures. Subsequently, the open collector output switches to the appropriate state. WSH130NL are rated for operation over temperature range from  $-40^{\circ}$  C to 125  $^{\circ}$ C and voltage ranges from 2.4V to 26V.

#### **Pin Descriptions:**

Name	P/I/O	Pin#	Description			
Vdd	P	1	Positive Power Supply			
Gnd	О	2	Ground			
Vout	О	3	Output Pin			

#### Absolute Maximum Rating (at Ta=25°C)

Supply Voltage	Vcc	26V
Output breakdown Voltage	$Vout_{(breakdown)} - \!$	30V





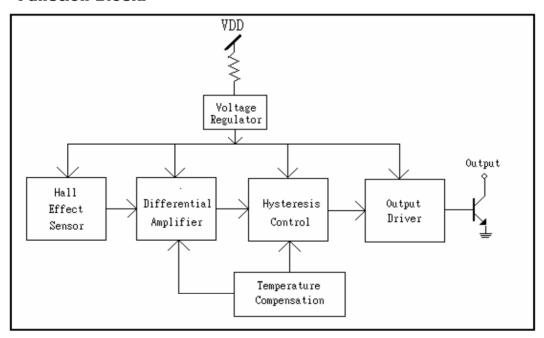
Magnetic flux density	В	 Unlimited
Reverse Protection Voltage	Vr	 26V
Output ON Current (continuous)	Ic	 25mA
Operating Temperature Range	Ta	 $(-40^{\circ}\text{C to } + 125^{\circ}\text{C})$
Storage Temperature Range	Ts	 $(-65^{\circ}\text{C to } +150^{\circ}\text{C})$
Package Power Dissipation	Pd	 500mw

#### **Electrical Characteristics:**

$(T=+25^{\circ}C,$	$V_{CC}=2.4V$	to 26V)
11-743 0.	V CC— <b>∠.</b> + V	10 40 V

Characteristic	Symbol	<b>Test Conditions</b>	Min	Тур	Max	Units
Supply Voltage	Vcc		2.4		26	V
Output Saturation Voltage	Vout (sat)	Vcc=12V,Ic=10mA B > Bop	_	0.2	0.6	V
Output Leakage Current	Ileakage	Vcc=12V, B <brp< td=""><td></td><td>&lt;0.1</td><td>10</td><td>uA</td></brp<>		<0.1	10	uA
Supply Current	Isupply	Vcc=12V,Output Open		4.0	8	mA
Output Rise Time	Tr	Vcc=12V,RL=2K Ω CL=20Pf		1.0	10	μs
Output Falling Time	Tf	Vcc=12V,RL=2K Ω CL=20Pf	_	0.3	1.5	$\mu$ s

#### **Function Block:**

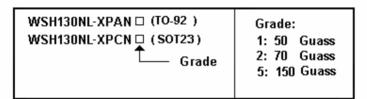




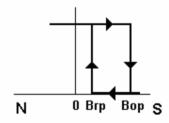
## **Magnetic Characteristics:**

Characteristic	Symbol	Grade	Min.	Тур.	Max.	Unit
Operating Point	Bop	A			+ 50	Guass
		В			+70	Guass
		С			+150	
Release Point	Brp	A	+10			Guass
		В	+10			Guass
		С	+10			Guass
Hysteresis Window	Bhys			10	30	Guass

## **Ordering Information:**

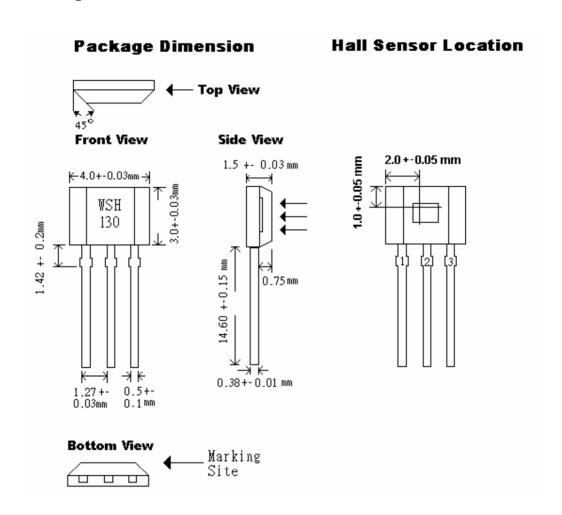


Output vs. Magnetic Field

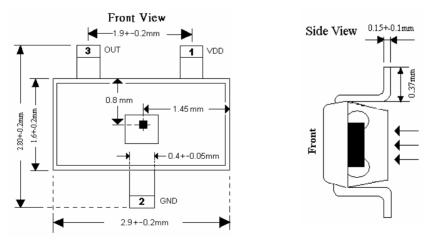




## **Package Information:**



#### SOT23:





# **Application Circuit:**

# Magnetic detector:

